

Effects of the electrostatic environment on superlattice Majorana nanowires



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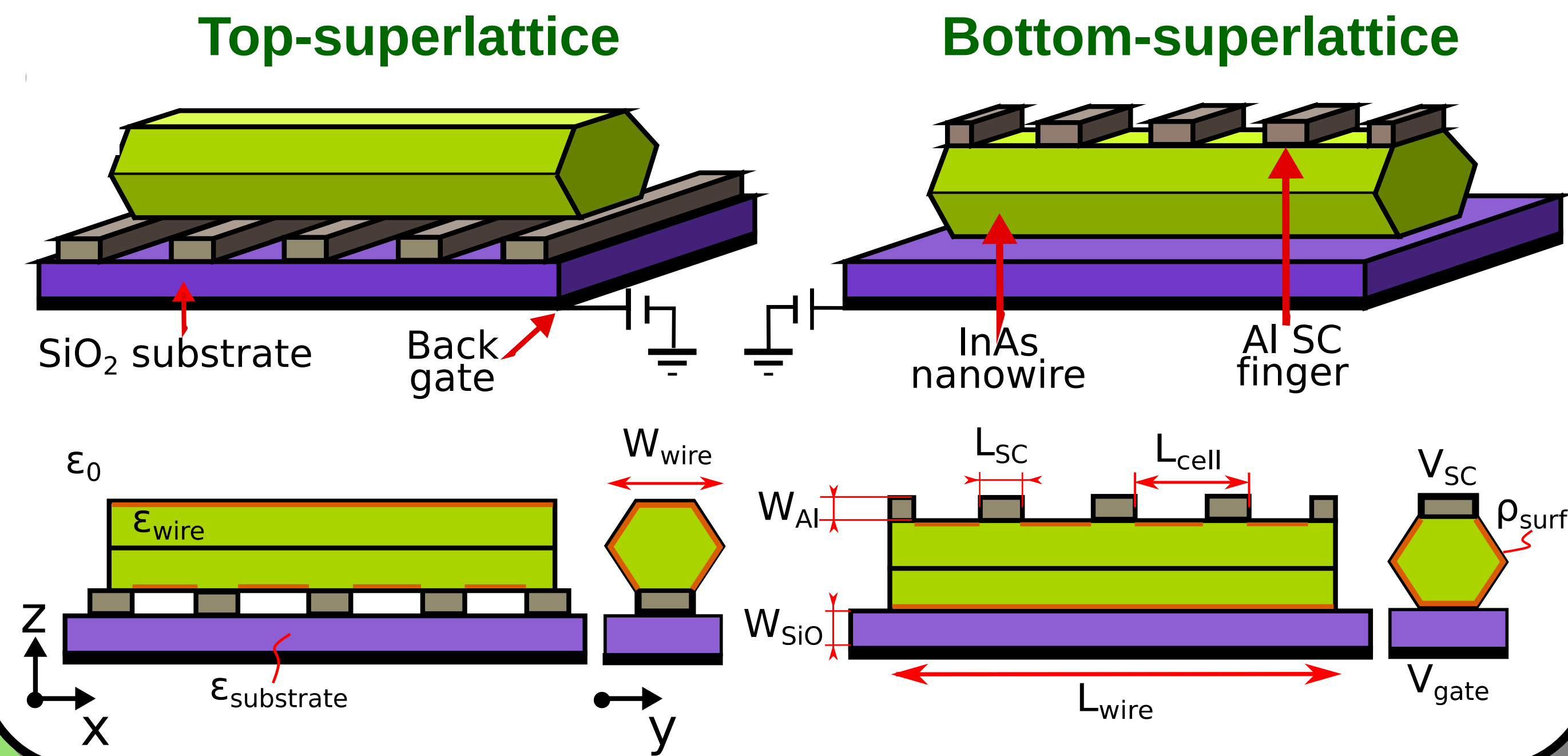
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ABSTRACT: Finding ways of creating, measuring and manipulating Majorana bound states (MBSs) in superconducting-semiconducting nanowires is a highly pursued goal in condensed matter physics. It was recently proposed [1] that a periodic covering of the semiconducting nanowire with superconductor (SC) fingers would allow both gating and tuning the system into a topological phase while leaving room for a local detection of the MBS wavefunction. Here we perform a detailed, self-consistent numerical study of a 3D model for a finite length nanowire with a SC superlattice including the effect of the surrounding electrostatic environment. We find that the analysis of the electrostatic potential, the low energy spectrum and the formation of MBSs reveals a rich phenomenology that depends on the nanowire parameters as well as on the superlattice dimensions and the external back gate potential.

1. Superlattice setups



2. Methods

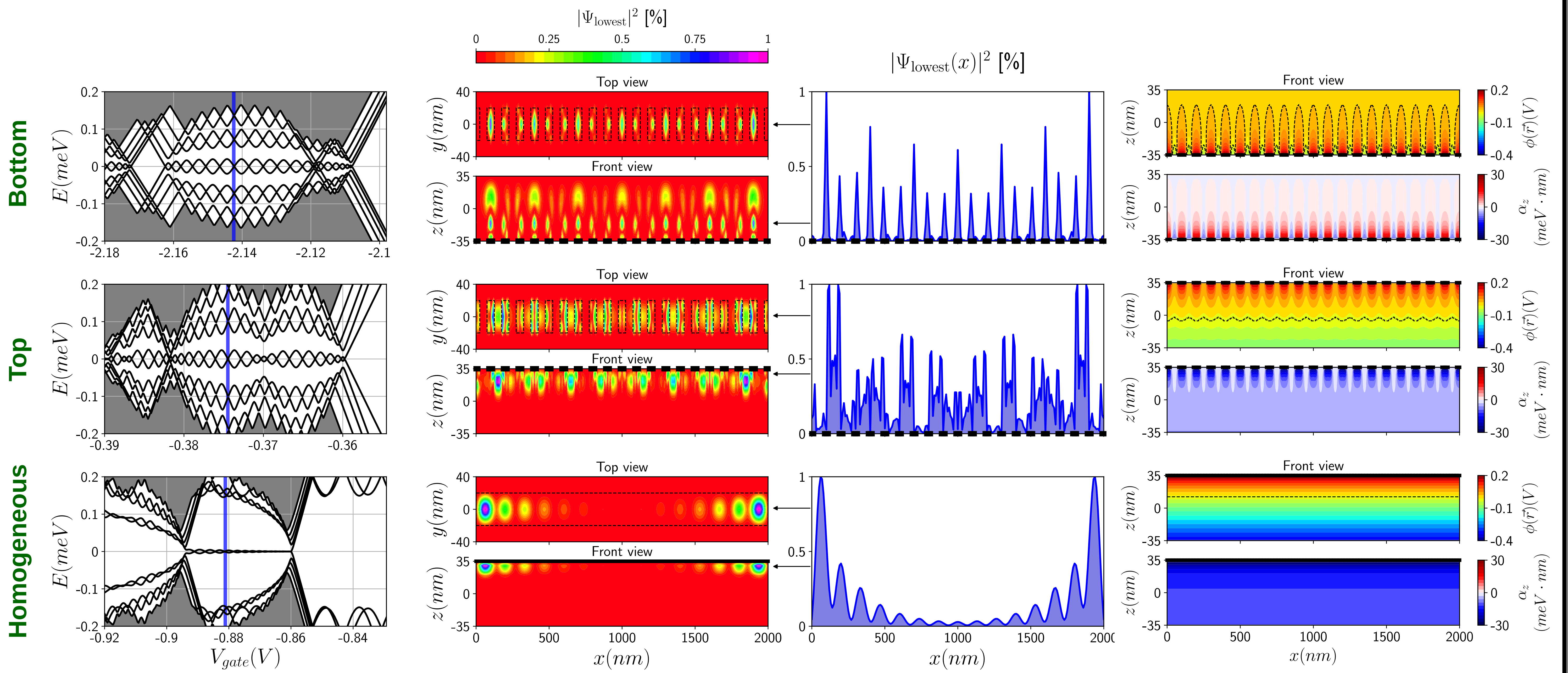
We solve self-consistently the 3D Schrödinger-Poisson equation in the Thomas-Fermi approximation,

$$\hat{H}(\vec{r}) = \left[\frac{\hbar^2 k^2}{2m^*} - e\phi(\vec{r}) - E_F \right] \hat{\sigma}_0 \hat{\tau}_z - \frac{i}{2} \hat{\sigma} \cdot \left(\vec{\alpha}_R(\vec{r}) \times \vec{k} \right) \hat{\tau}_z + V_Z \hat{\sigma}_x \hat{\tau}_z - i\Delta(\vec{r}) \hat{\sigma}_y \hat{\tau}_y,$$

where the three inhomogeneous parameters are given by,

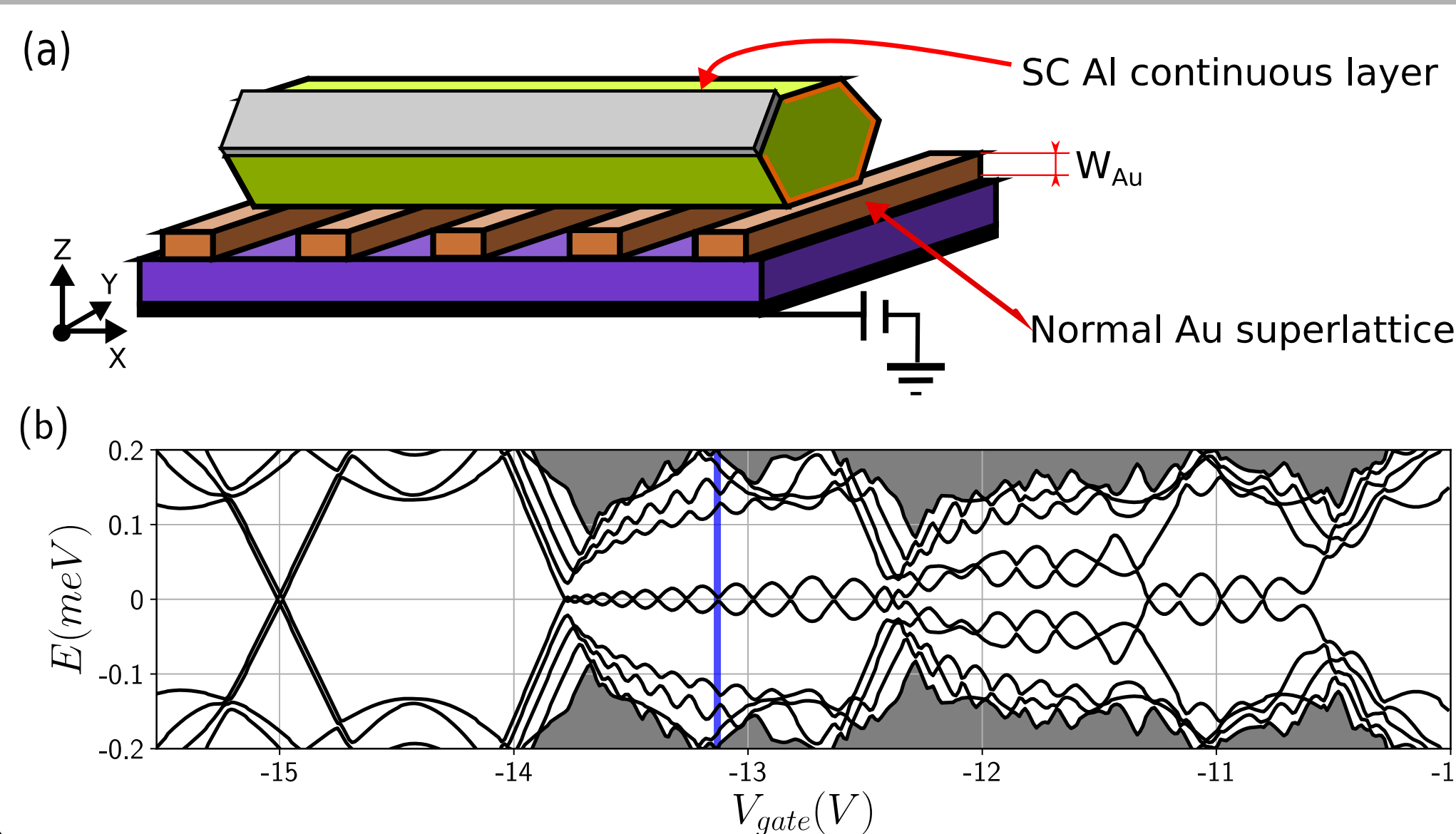
- The Poisson equation: $\vec{\nabla}(\epsilon(\vec{r}) \cdot \vec{\nabla} \phi(\vec{r})) = \rho_e^{(TF)}[\phi(\vec{r})] + \rho_{surf}$
- An 8-band k·p model: $\vec{\alpha}(\vec{r}) = \vec{\alpha}_{int} + \frac{eP^2}{3} \left[\frac{1}{E_{cv}^2} - \frac{1}{(E_{cv} + E_{vv})^2} \right] \vec{\nabla} \phi(\vec{r})$
- A rigid boundary condition: $\Delta(\vec{r}) = \begin{cases} \Delta_0 & \text{if } \vec{r} \in \Omega_{SC} \\ 0 & \text{else} \end{cases}$

3. Results

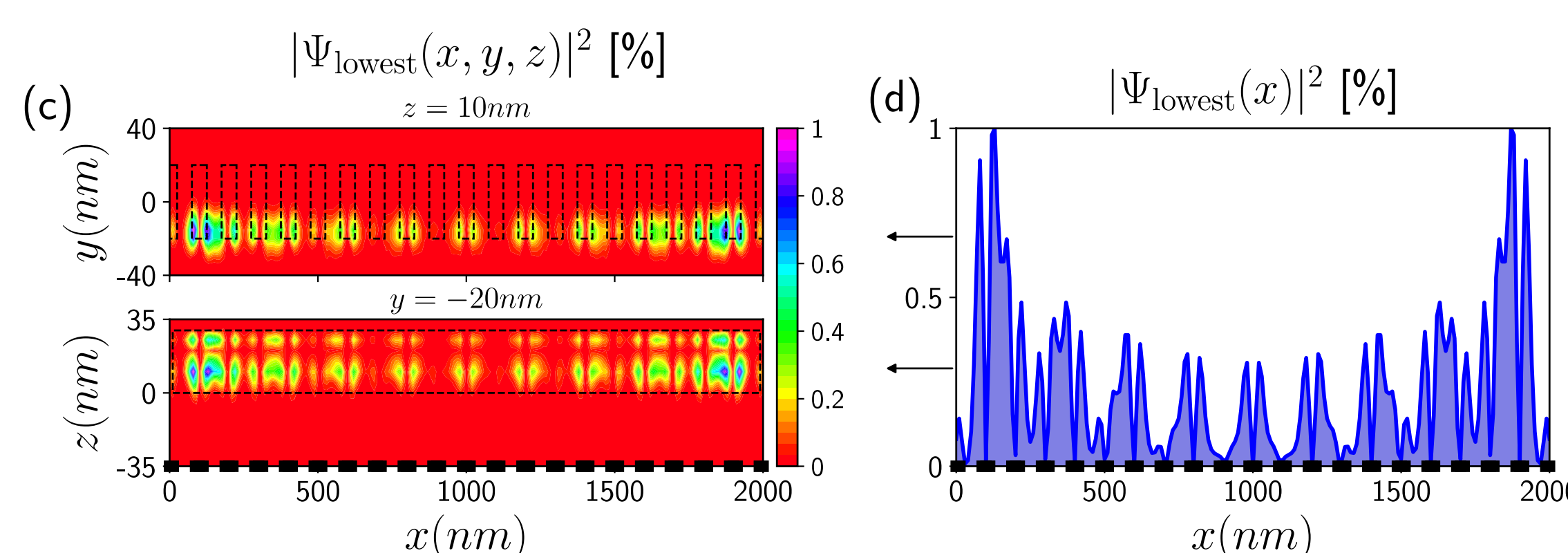


- In comparison to the homogeneous case, the energy spectra of the superlattice devices show: emergence of **localized states** which interact with the MBSs, **longitudinal minibands** (not shown here), and a **smaller minigap**.
- The lowest-energy modes of the superlattice setups exhibit a Majorana-like profile. However, (1) they have **additional** (faster) **oscillations**, (2) they **overlap more** (are more extended), (3) they are not as much localized close to the SC as in the homogeneous case.
- The **electrostatic potential exhibits oscillations** (larger in the Bottom device) that leads to the creation of localized states.
- This **oscillations creates a larger unit cell**, which leads to the folding of the bands, creating the longitudinal subbands.
- The **Rashba coupling varies along and the wire length**. Since **on average is smaller**, so does the topological protection.

4. Alternative configuration



- When one lateral facet is covered by a SC continuous layer in the bottom-superlattice, we find a comparable topological protection to the homogeneous one.



Further details.-

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Parameters.-

$L=2\mu\text{m}$, $W=80\text{nm}$, $W_{Al}=8\text{nm}$, $W_{SiO_2}=20\text{nm}$, $L_{cell}=100\text{nm}$, $L_{SC}=50\text{nm}$, $V_{Al}=0.2\text{eV}$, $V_Z=0.7\text{meV}$, $\rho_{surf}=2 \cdot 10^{-4} \text{e} \cdot \text{nm}^{-3}$.

References.-

[1] Yoav Levine, Arbel Haim, and Yuval Oreg, *Phys. Rev. B* **96**, 165147 (2017).